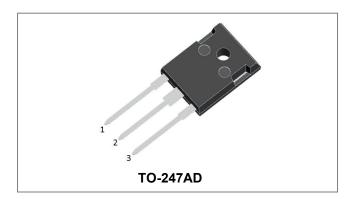


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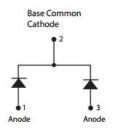
# SDUR6060WT ULTRAFAST RECTIFIER



### Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### **Circuit Diagram**



#### Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm V <sub>rwm</sub> Vr	-	600	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=70°C, rectangular wave form	30(Per Leg) 60(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	300	А

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 30A, Pulse, T <sub>J</sub> = 25°C	1.70	1.80	V
Reverse Current (Per Leg)*	I <sub>R1</sub>	$@V_R = rated V_{R, T_J} = 25^{\circ}C$	2	250	uA
	I <sub>R2</sub>	$@V_R = rated V_{R, T_J} = 125^{\circ}C$	1	2	mA
Reverse Recovery Time (Per Leg)	t <sub>rr</sub>	$t_{rr}$ I <sub>F</sub> =500mA,I <sub>R</sub> =1A,and I <sub>rm</sub> =250mA		50	ns

\* Pulse width < 300  $\mu$ s, duty cycle < 2%

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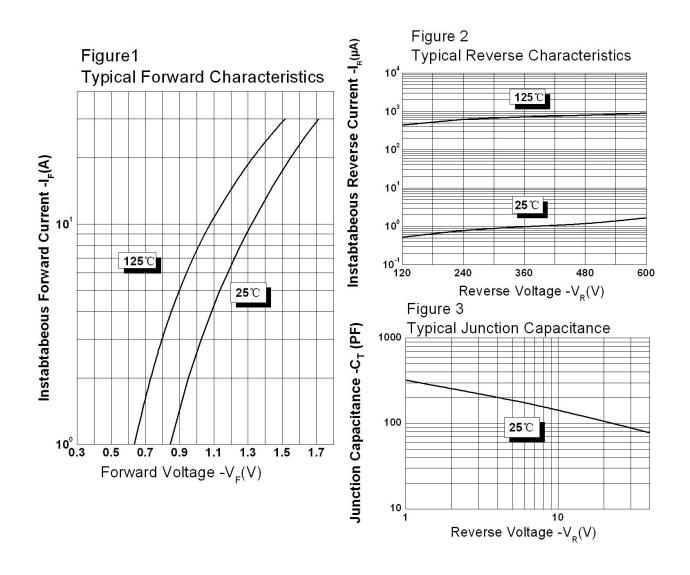
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RoHS 🗭

### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Symbol Condition		Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	1.15	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AD			

### **Ratings and Characteristics Curves**



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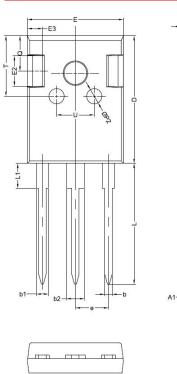
RoHS

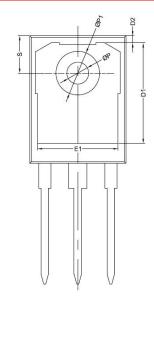
Pb

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### **Mechanical Dimensions TO-247AD**

A2





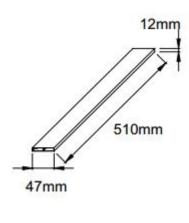
	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
А	4.80	5.00	5.20		
A1	2.20	2.41	2.61		
A2	1.90	2.00	2.10		
b	1.10	1.20	1.40		
b1	1.80	2.00	2.20		
b2	2.80	3.00	3.20		
С	0.50	0.60	0.75		
D	20.30	21.00	21.20		
D1		16.55			
D2		1.20			
D2 E	15.45	15.80	16.00		
E1		13.30			
E2		5.00			
E3		2.50			
е		5.44			
L	19.42	19.92	20.70		
L1		4.13			
Р	3.50	3.60	3.70		
P1	7.1		7.40		
P2		2.50			
Q		5.80			
S T	6.05	6.15	6.25		
Т		10.00			
U		6.20			

### **Ordering Information:**

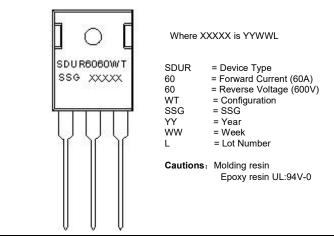
Device	Package	Shipping	
SDUR6060WT	TO-247AD(Pb-Free)	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

### **Tube Specification**



### **Marking Diagram**



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## SDUR6060WT



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